



# NES

## NEW ENGLAND SEMICONDUCTOR

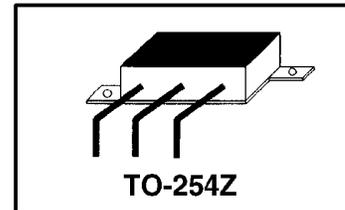
### NSG2561

## LOW DROPOUT VOLTAGE REGULATORS

3 TERMINAL  
POSITIVE  
ADJUSTABLE

- 1V Dropout, 1.5V @ Max Current
- 0.01% Load Regulation
- 0.015% Line Regulation
- 1% Reference Voltage
- Hermetic TO-254Z Pak
- Output Current 1.5A

Pinout	
Pin 1	Adjust
Pin 2	Vout
Pin 3	Vin

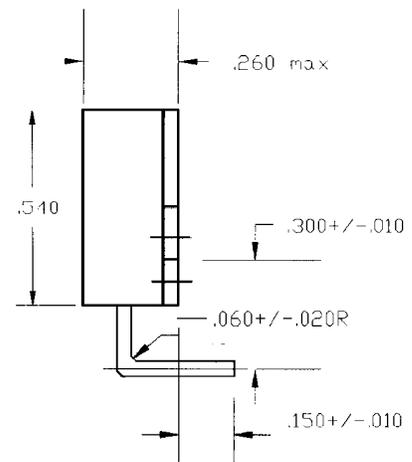
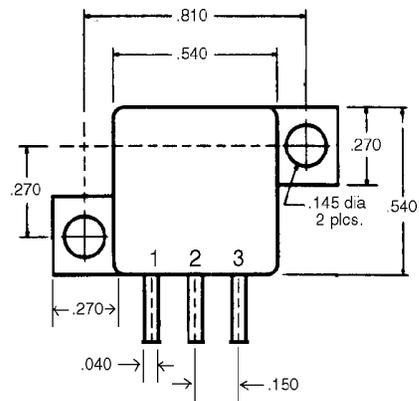


TO-254Z

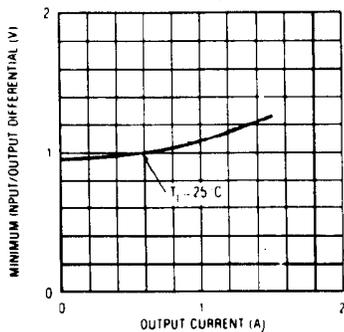
### ABSOLUTE MAXIMUM RATINGS

Power Dissipation.....	15 W
Operating Junction Temperature Range.....	- 55°C to + 150°C
Storage Temperature.....	- 65°C to + 150°C
Output Current--	
NSG2561.....	1.5 A
Input Voltage.....	35 V

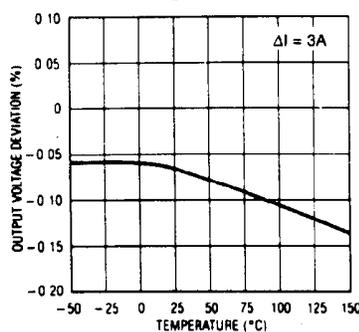
### MECHANICAL OUTLINE



#### Dropout Voltage



#### Load Regulation



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6 Lake Street Lawrence, MA 01841  
1-800-446-1158 / (978) 794-1666 / FAX: (978) 689-0803

T4-4.8-860-038 REV: --



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NEW ENGLAND SEMICONDUCTOR

**NSG2561**

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}\text{C}$  unless otherwise noted)

Parameter	Conditions	NSG2561			Units
		Min	Typ	Max	
Line Regulation	$I_L = 10 \text{ mA}$ , $1.5\text{V} \leq  V_{IN} - V_{OUT}  \leq 15\text{V}$ $T_j = 25^{\circ}\text{C}$		0.015	0.2	%
			0.035	0.2	%
	$15\text{V} \leq  V_{IN} - V_{OUT}  \leq 35\text{V}^{(1\&2)}$		0.05	0.5	%
Load Regulation	$ V_{IN} - V_{OUT}  = 3 \text{ V}$ $10 \text{ mA} \leq I_{OUT} \leq I_{FULL\,LOAD}$ $T_j = 25^{\circ}\text{C}$ (1,2,3)		0.1	0.3	%
			0.2	0.4	%
Thermal Regulation NSG2561	$T_A = 25^{\circ}\text{C}$ , 30 ms Pulse		0.010	0.05	%/W
Adjustment Pin Current Change	$10 \text{ mA} \leq I_{OUT} \leq I_{FULL\,LOAD}$ $1.5 \text{ V} \leq  V_{IN} - V_{OUT}  \leq 25\text{V}$		0.2	5	$\mu\text{A}$
Adjustment Pin Current	$T_j = 25^{\circ}\text{C}$		55		$\mu\text{A}$
Reference Voltage	$I_{OUT} = 10 \text{ mA}$ , $T_j = 25^{\circ}\text{C}$ $ V_{IN} - V_{OUT}  = 3 \text{ V}$ $10 \text{ mA} \leq I_{OUT} \leq I_{FULL\,LOAD}$ $1.5 \text{ V} \leq  V_{IN} - V_{OUT}  \leq 25 \text{ V}^{(3)}$	1.238	1.250	1.262	V
		1.225	1.250	1.270	V
Temperature Stability	$-55^{\circ}\text{C} \leq T_j \leq +150^{\circ}\text{C}$		0.5		%
Minimum Load Current	$ V_{IN} - V_{OUT}  = 25\text{V}$		5	10	mA
Current Limit NSG2561	$ V_{IN} - V_{OUT}  = 5\text{V}$ $ V_{IN} - V_{OUT}  = 25\text{V}$		1.8		A
			0.2		A
RMS Output Noise (% of $V_{OUT}$ )	$T_A = 25^{\circ}\text{C}$ , $10 \text{ Hz} \leq f \leq 10 \text{ kHz}$		0.003		%
Ripple Rejection Ratio	$f = 120 \text{ Hz}$ $C_{ADJ} = 25 \mu\text{F Tantalum}$ $I_{OUT} = I_{FULL\,LOAD}$ $ V_{IN} - V_{OUT}  = 3\text{V}$	60	75		dB
Long-Term Stability	$T_A = 125^{\circ}\text{C}$ , 1000 Hours		0.3	1	%
Dropout Voltage	$\Delta V_{REF} = 1\%$ , $I_{OUT} = I_{FULL\,LOAD}$		1.3	1.5	V

- 1) Load and line regulation are measured at a constant junction temperature by low duty cycle pulse testing.
- 2) Line and load regulation are guaranteed up to the maximum power dissipation.
- 3)  $I_{FULL\,LOAD}$  curve is defined as the minimum value of current limit as a function of input to output voltage. Note that power dissipation is only achievable over a limited range of input to output voltage.

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